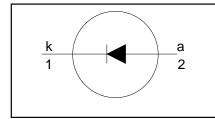
# Rectifier diodes Schottky barrier

# PBYL1625 series

## **FEATURES**

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

## **SYMBOL**



## **QUICK REFERENCE DATA**

$$V_R = 20 \text{ V/ } 25 \text{ V}$$
 $I_{F(AV)} = 16 \text{ A}$ 
 $V_F \le 0.46 \text{ V}$ 

#### **GENERAL DESCRIPTION**

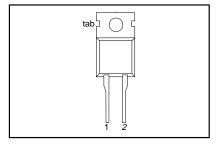
Schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL1625 series is supplied in the SOD59 (TO220AC) conventional leaded package.

## **PINNING**

PIN	DESCRIPTION	
1	cathode	
2	anode	
tab	cathode	

# SOD59 (TO220AC)



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER CONDITIONS MIN. MAX.		XX.	UNIT		
		PBYL16		20	25	
$V_{RRM}$	Peak repetitive reverse		-	20	25	V
$V_{RWM}$	voltage Working peak reverse voltage		-	20	25	V
$V_R$	Continuous reverse voltage	T <sub>mb</sub> ≤ 120 °C	-	20	25	V
I <sub>F(AV)</sub>	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 131$ °C	-	1	6	Α
I <sub>FRM</sub>	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \le 131$ °C	-	3	2	Α
I <sub>FSM</sub>	Non-repetitive peak forward current	t = 10  ms t = 8.3  ms sinusoidal; $T_i = 125 ^{\circ}\text{C}$ prior to surge; with reapplied $V_{\text{RRM(max)}}$	-		35 50	A A
I <sub>RRM</sub>	Peak repetitive reverse	pulse width and repetition rate	-	1		Α
T <sub>j</sub>	surge current Operating junction temperature	limited by T <sub>j max</sub>	-	15	50	°C
$T_{stg}$	Storage temperature		- 65	17	75	°C

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# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction		-	-	2	K/W
R <sub>th j-a</sub>	to mounting base Thermal resistance junction to ambient	in free air	-	60	-	K/W

# **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	I <sub>F</sub> = 16 A; T <sub>i</sub> = 125°C	1	0.42	0.46	V
·		$I_{\rm F} = 32  \text{A}, T_{\rm i} = 125  ^{\circ} \text{C}$	-	0.57	0.61	V
		$I_{\rm F} = 32  {\rm A}^{-1}$	-	0.55	0.68	V
I <sub>R</sub>	Reverse current	$\dot{V}_{R} = V_{RWM}$	-	1	5	mΑ
"		$V_R = V_{RWM}$ ; $T_i = 100$ °C	-	22	40	mΑ
C <sub>d</sub>	Junction capacitance	$V_{R} = 5 \text{ V}; \text{ f} = 1 \text{ MHz}, T_{j} = 25 ^{\circ}\text{C} \text{ to } 125 ^{\circ}\text{C}$	-	700	-	pF

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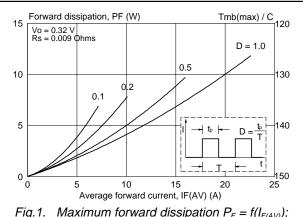


Fig.1. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

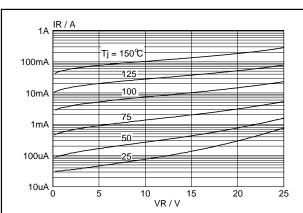


Fig.4. Typical reverse leakage current;  $I_R = f(V_R)$ ; parameter  $T_j$ 

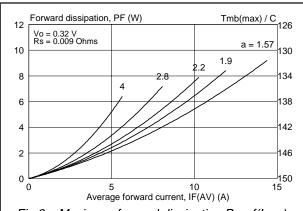


Fig.2. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; square current waveform where  $I_{F(AV)} = I_{F(RMS)} x \sqrt{D}$ .

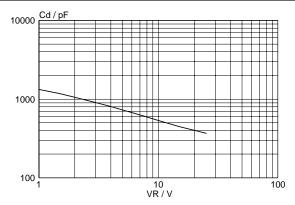


Fig.5. Typical junction capacitance;  $C_d = f(V_R)$ ; f = 1 MHz;  $T_j = 25 ^{\circ}\text{C}$  to  $125 ^{\circ}\text{C}$ .

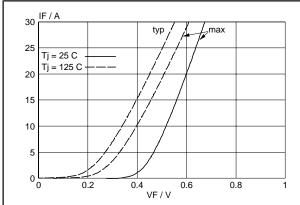
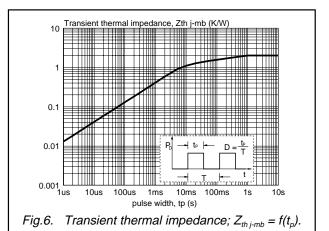
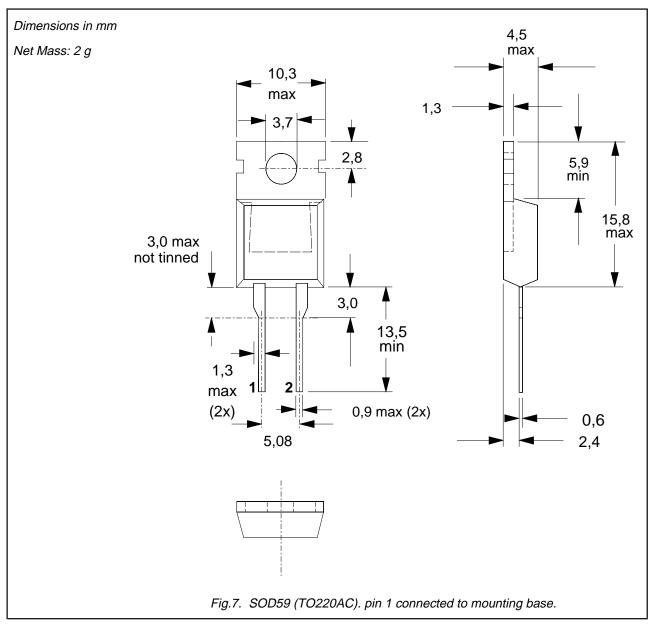


Fig.3. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_i$ 



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## **MECHANICAL DATA**



- Refer to mounting instructions for TO220 envelopes.
   Epoxy meets UL94 V0 at 1/8".

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#### **DEFINITIONS**

Data sheet status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification This data sheet contains preliminary data; supplementary data may be published later			
Product specification	This data sheet contains final product specifications.		
Limiting values			

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

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